

Dual N-Channel Enhancement MOSFET

Description

WM02DN70M3 uses advanced power trench technology that has been especially tailored to minimize the on-state resistance. This device is suitable for un-directional or bidirectional load switch, facilitated by its common-drain configuration.

$V_{(BR)DSS}(V)$	$I_D(A)$	$R_{DS(on)TYP}(m\Omega)$
20	7	11.5 @VGS=10V
		13 @VGS=4.5V
		15 @VGS=2.5V

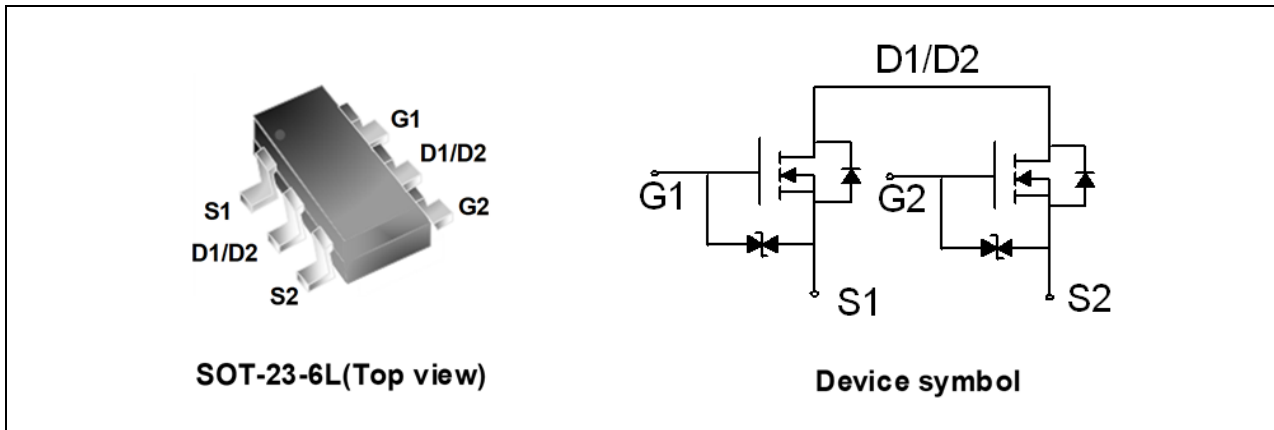
Features

- Super high dense cell for low $R_{DS(ON)}$
- RoHS Compliant & Halogen-Free
- ESD protected: Class 1C

Applications

- Battery protection
- Load switch

Schematic & PIN Configuration



Absolute Maximum Rating ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current	I_D	$T_A=25^{\circ}C$	7
		$T_A=100^{\circ}C$	4.4
Pulsed Drain Current ¹	I_{DM}	28	A
Total Power Dissipation	P_D	1.7	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^{\circ}C$

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction-to-Ambient ²	$R_{\theta JA}$	73.5	$^{\circ}C/W$

Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	20	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0V			1	μA
Gate-body Leakage current	I _{GSS}	V _{DS} = 0V, V _{GS} = ±10V	-	-	±10	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	0.4	0.6	1	V
Drain-Source on-Resistance ³	R _{DS(on)}	V _{GS} = 10V, I _D = 7A	-	11.5	17	mΩ
		V _{GS} = 4.5V, I _D = 6.5A	-	13	19.5	
		V _{GS} = 2.5V, I _D = 6A	-	15	21	
Forward Transconductance ³	g _{fs}	V _{DS} = 5V, I _D = 7A	-	12	-	S
Dynamic Characteristics⁴						
Input Capacitance	C _{iss}	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	-	695	-	pF
Output Capacitance	C _{oss}		-	110	-	
Reverse Transfer Capacitance	C _{rss}		-	97	-	
Switching Characteristics⁴						
Total Gate Charge	Q _g	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 7A	-	9.6	-	nC
Gate-Source Charge	Q _{gs}		-	1.9	-	
Gate-Drain Charge	Q _{gd}		-	1.7	-	
Turn-on Delay Time	t _{d(on)}	V _{GS} = 4.5V, V _{DD} = 10V R _G = 3Ω, I _D = 7A	-	5.3	-	ns
Rise Time	t _r		-	4.1	-	
Turn-off Delay Time	t _{d(off)}		-	8.4	-	
Fall Time	t _f		-	3.5	-	
Drain-Source Diode Characteristics						
Diode Forward Voltage ³	V _{SD}	I _S = 1A, V _{GS} = 0V	-	-	1.2	V
Continuous Source Current	I _S	-	-	-	7	A

Notes:

1. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C.
2. The data tested by surface mounted on a 1 inch² FR-4 board with 20Z copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.
4. This value is guaranteed by design hence it is not included in the production test.

Typical Characteristics

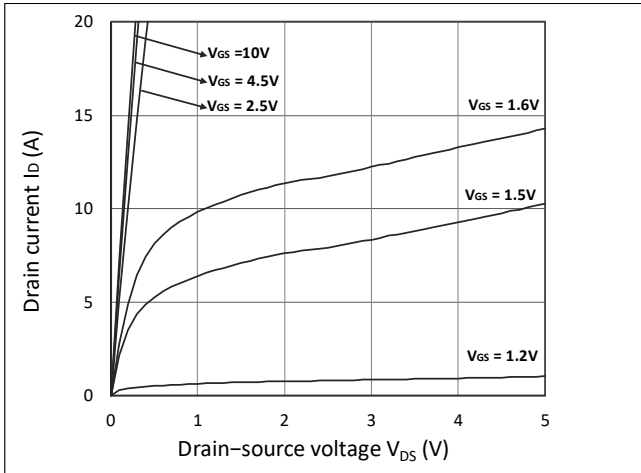


Figure 1. Output Characteristics

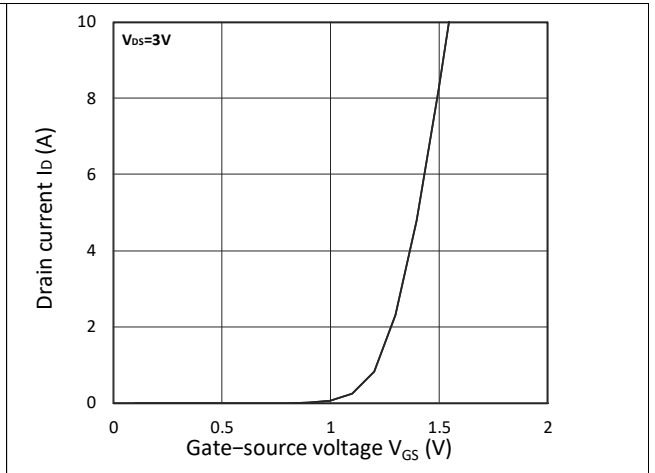


Figure 2. Transfer Characteristics

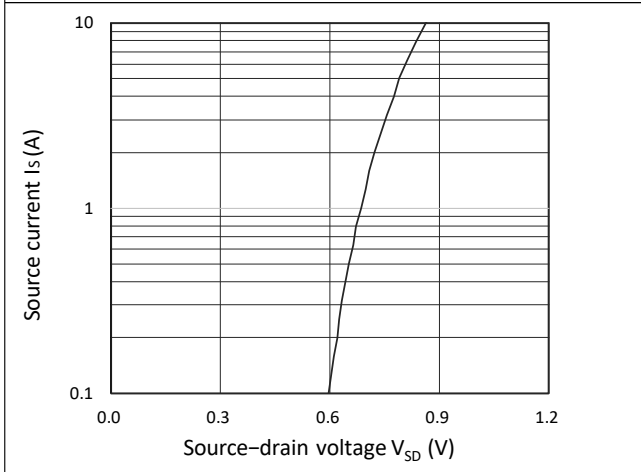


Figure 3. Forward Characteristics of Reverse

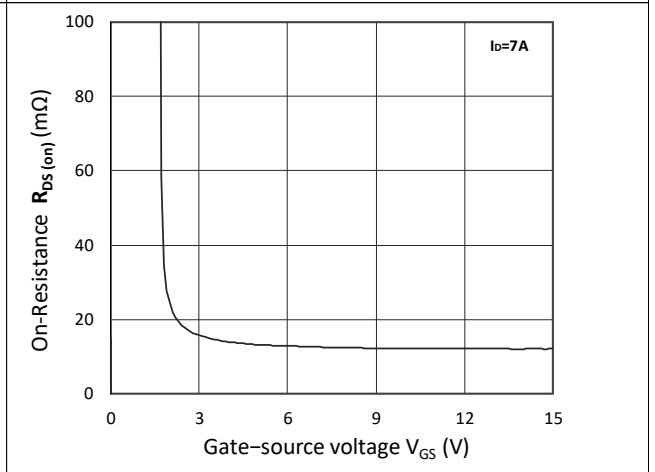


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

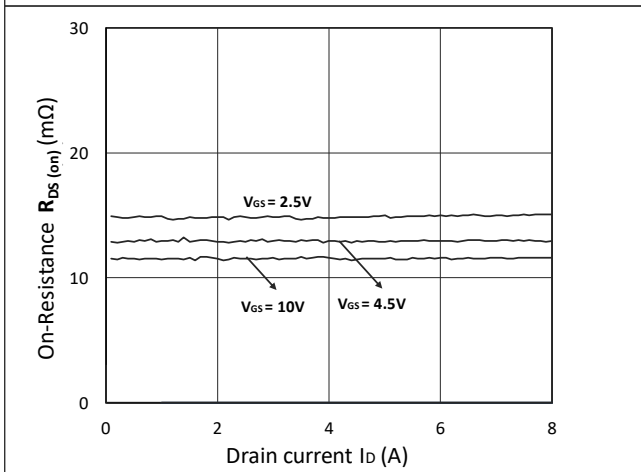


Figure 5. $R_{DS(ON)}$ vs. I_D

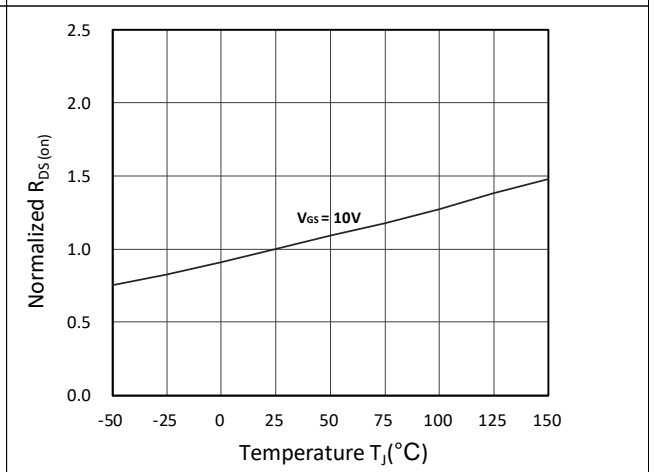


Figure 6. Normalized $R_{DS(ON)}$ vs. Temperature

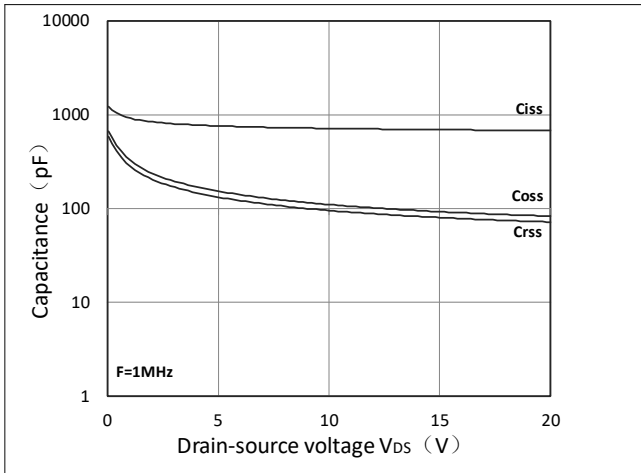


Figure 7. Capacitance Characteristics

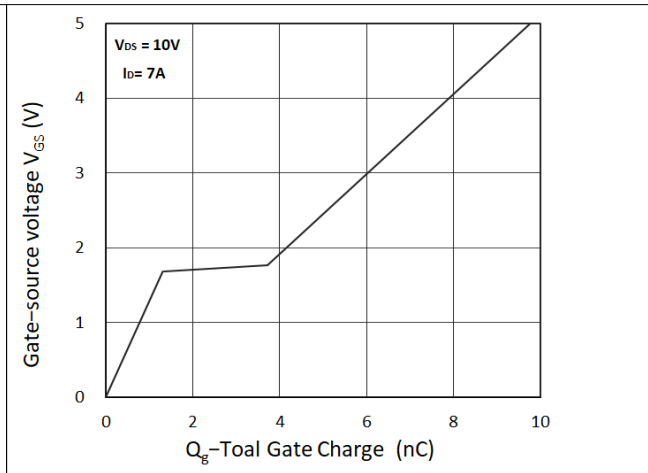
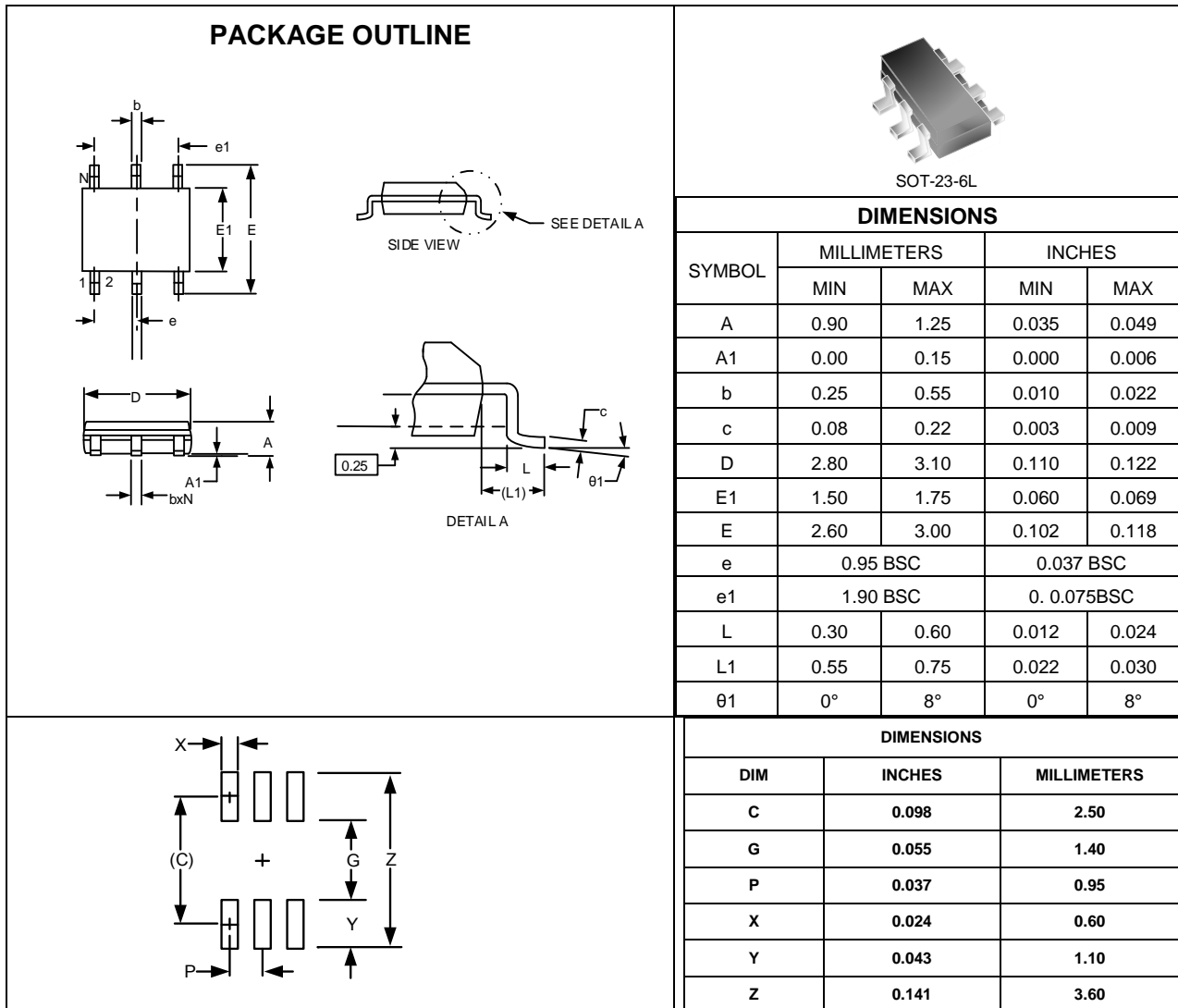


Figure 8. Gate Charge Characteristics

Outline Drawing –SOT-23-6L



Marking Codes

Part Number	WM02DN70M3
Marking Code	

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

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